

Description

The AU1531D5 is a uni-directional TVS diode, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive data and power line. The AU1531D5 complies with the IEC 61000-4-2 (ESD) with $\pm 25\text{kV}$ air and $\pm 20\text{kV}$ contact discharge. It is assembled into an ultra-small lead-free DFN package. The small size and high ESD surge protection make AU1531D5 an ideal choice to protect cell phone, digital cameras, audio players and many other portable applications.

Features

- Ultra small package: SOD-523
- Protects one data or power line
- Ultra low leakage: nA level
- Operating voltage: 15V
- Low clamping voltage
- 2-pin leadless package
- Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test
 - Air discharge: $\pm 25\text{kV}$
 - Contact discharge: $\pm 20\text{kV}$
 - IEC61000-4-5 (Lightning) 4A (8/20 μs)
- RoHS Compliant

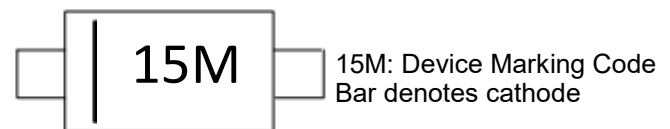
Mechanical Characteristics

- Package: SOD-523
- Case Material: “Green” Molding Compound.
- Terminal Connections: See Diagram Below
- Marking Information: See Below

Applications

- Cellular Handsets and Accessories
- Personal Digital Assistants
- Notebooks and Handhelds
- Portable Instrumentation
- Power Supply
- Keypads, Side Keys, LCD Displays

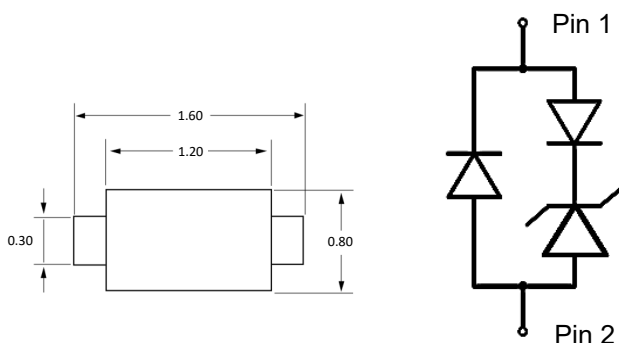
Marking Information



Ordering Information

Part Number	Packaging	Reel Size
AU1531D5	3000/Tape & Reel	7 inch

Dimensions and Pin Configuration



Package Dimensions (mm) Circuit and Pin Schematic

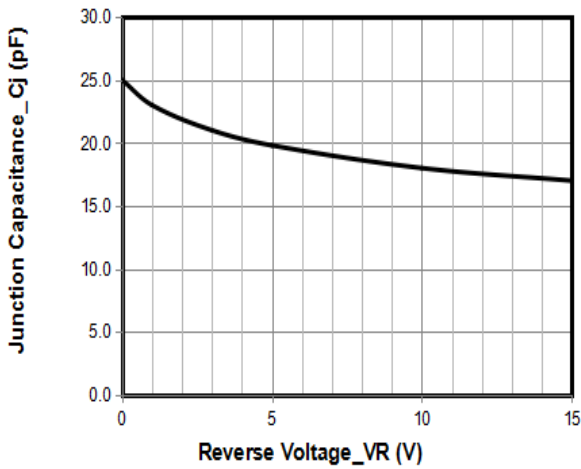
Absolute Maximum Ratings ($T_A=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20 μs)	Ppk	100	W
Peak Pulse Current (8/20 μs)	Ipp	4	A
ESD per IEC 61000-4-2 (Air)	VESD	± 25	kV
ESD per IEC 61000-4-2 (Contact)		± 20	
Operating Temperature Range	TJ	-55 to +125	$^\circ\text{C}$
Storage Temperature Range	Tstg	-55 to +150	$^\circ\text{C}$

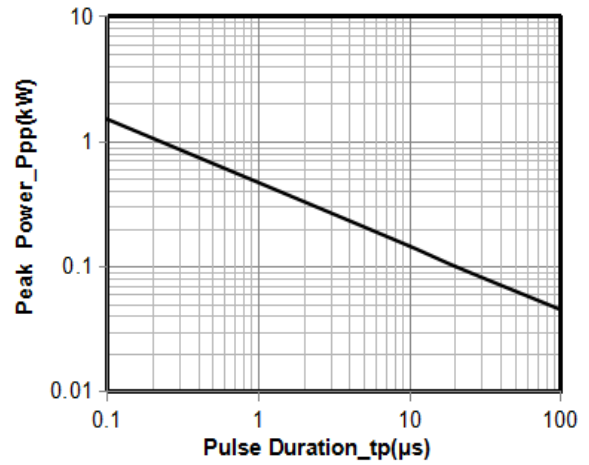
Electrical Characteristics ($T_A=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	VRWM			15	V	Pin 1 to Pin 2
Breakdown Voltage	VBR	16.5			V	IT = 1mA, Pin 1 to Pin 2
Reverse Leakage Current	IR			0.2	μA	VRWM = 15V, Pin 1 to Pin 2
Forward Voltage	VF			1.2	V	IF = 10mA, Pin 2 to Pin 1
Clamping Voltage	VC			21	V	IPP = 1A (8 x 20 μs pulse), Pin 1 to Pin 2
Clamping Voltage	VC			25	V	IPP = 4A (8 x 20 μs pulse), Pin 1 to Pin 2
Junction Capacitance	CJ		25		pF	VR = 0V, f = 1MHz

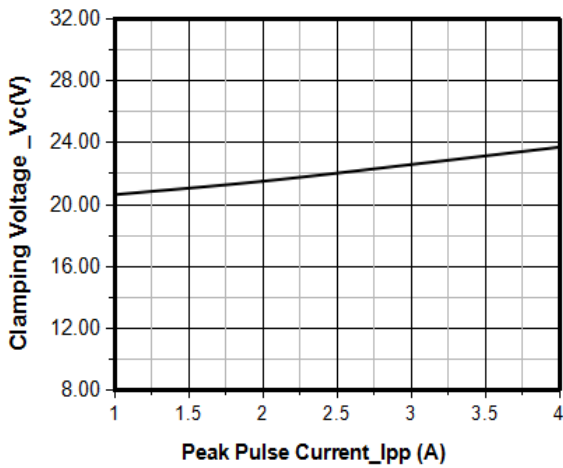
Typical Performance Characteristics ($T_A=25^\circ\text{C}$ unless otherwise Specified)



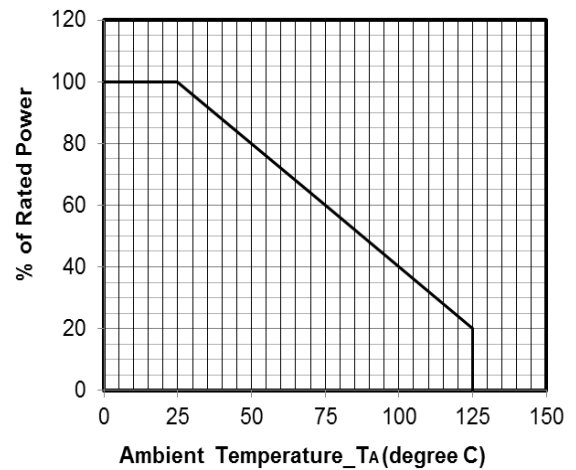
Junction Capacitance vs. Reverse Voltage



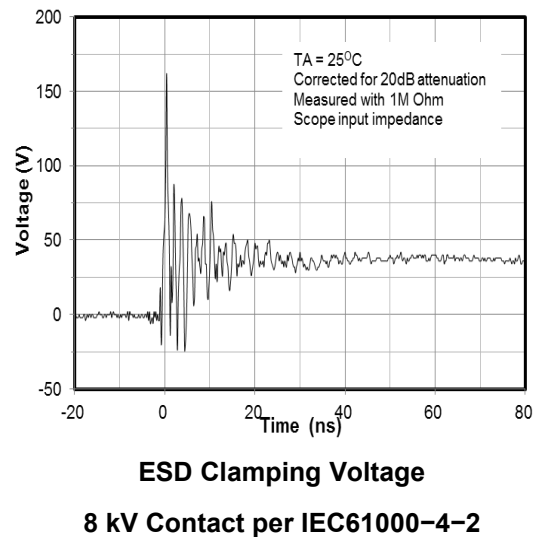
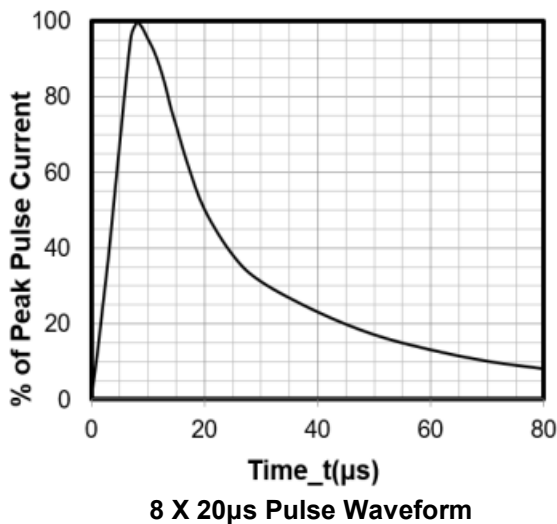
Peak Pulse Power vs. Pulse Time

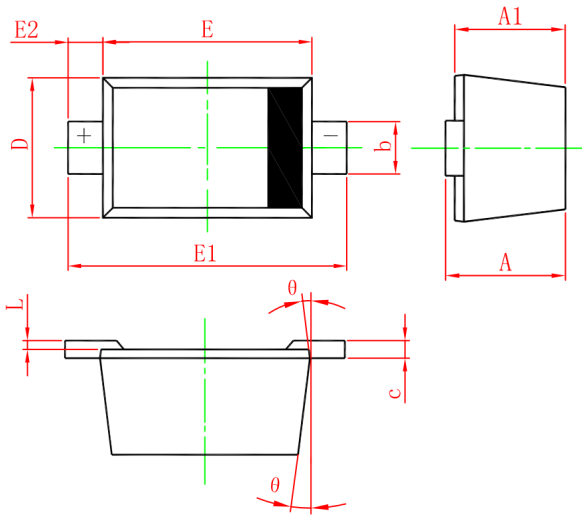


Clamping Voltage vs. Peak Pulse Current

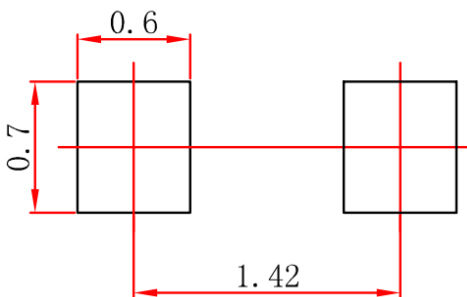


Power Derating Curve



SOD-523 Package Outline Drawing


SYM	DIMENSIONS					
	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.51	--	0.77	0.020	--	0.031
A1	0.50	--	0.70	0.020	--	0.028
b	0.25	--	0.35	0.010	--	0.014
c	0.08	--	0.15	0.003	--	0.006
D	0.75	--	0.85	0.030	--	0.033
E	1.10	--	1.30	0.043	--	0.051
E1	1.50	--	1.70	0.059		0.067
E2	0.20REF			0.008REF		
L	0.01	--	0.07	0.001	--	0.003
Θ	7° REF			7° REF		

Suggested Land Pattern


单位 (mm)

Contact Information

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